

Fast Soft Recovery Rectifier Diode, 20 A



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	20 A				
V_R	1200 V				
V _F at I _F	1.31 V				
I _{FSM}	320 A				
t _{rr}	95 ns				
T _J max.	150 °C				
Snap factor	0.6				
Package	TO-220AC 2L				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification



- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV/HEV battery chargers
- Input rectification

DESCRIPTION

The VS-20ETF12THM3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNI								
V _{RRM}		1200	V					
I _{F(AV)}	Sinusoidal waveform	20	Δ.					
I _{FSM}		320	A					
t _{rr}	1 A, 100 A/μs	95	ns					
V _F	20 A, T _J = 25 °C	1.31	V					
TJ	Range	-40 to +150	°C					

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
VS-20ETF12THM3	1200	1300	6					

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T _C = 113 °C, 180° conduction half sine wave	20				
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	270	Α			
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	320				
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	365	A ² s			
waximum i-t for fusing	ı-l	10 ms sine pulse, no voltage reapplied	515	A-S			
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	5150	A²√s			



ELECTRICAL SPECIFICATIONS							
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS							
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C		1.31	V		
Forward slope resistance	r _t	T _{.1} = 150 °C	11.88	mΩ			
Threshold voltage	V _{F(TO)}	1J = 150 C		0.93	V		
Maximum rayaraa laakaga ayrrant	1	T _J = 25 °C	\/ _ ratad\/	0.1	mA		
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = rated V _{RRM}	6	IIIA		

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t _{rr}	In at 20 Anu	400	ns	I _{FM}		
Reverse recovery current	I _{rr}	I _F at 20 A _{pk} 25 Α/μs	6.1	Α	$t_a \mid t_b$		
Reverse recovery charge	Q _{rr}	25 °C	1.7	μC	dir/ dt Q _{rr}		
Snap factor	S	Typical	0.6		I _{RM(REC)}		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and st temperature range	orage	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.9		
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
wounting torque	maximum			12 (10)	(lbf · in)	
Marking device			Case style TO-220AC 2L	20ETF	12TH	

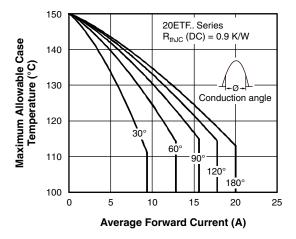


Fig. 1 - Current Rating Characteristics

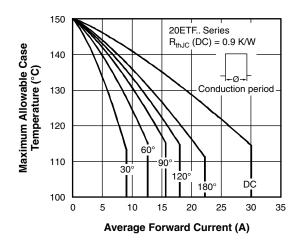


Fig. 2 - Current Rating Characteristics



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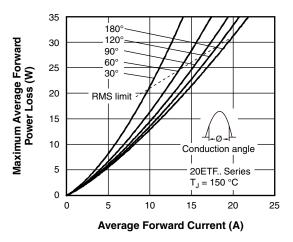


Fig. 3 - Forward Power Loss Characteristics

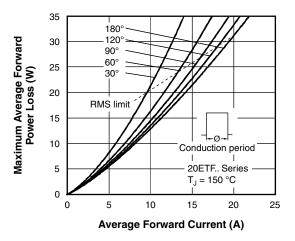


Fig. 4 - Forward Power Loss Characteristics

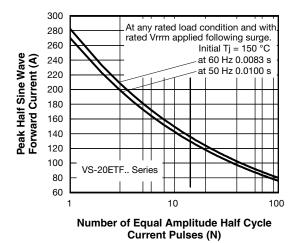


Fig. 5 - Maximum Non-Repetitive Surge Current

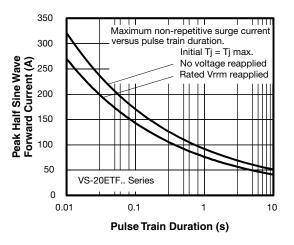


Fig. 6 - Maximum Non-Repetitive Surge Current

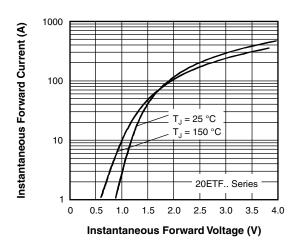


Fig. 7 - Forward Voltage Drop Characteristics

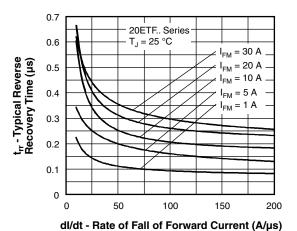


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \,^{\circ}\text{C}$



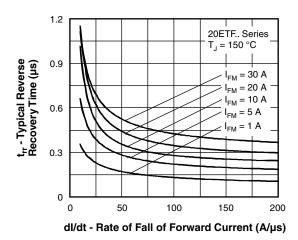


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

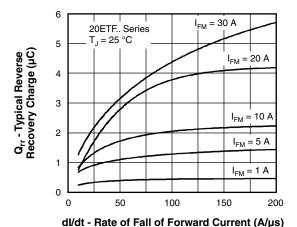
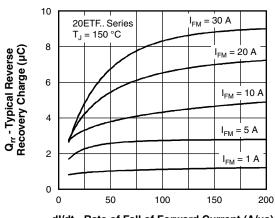


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

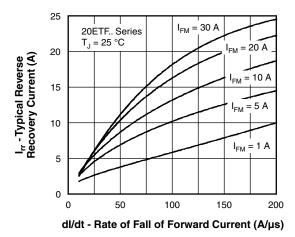


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

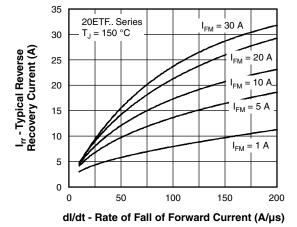


Fig. 13 - Recovery Current Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

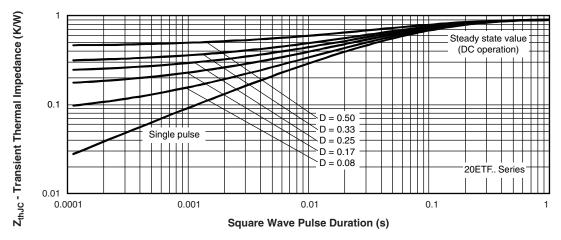


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code VS-20 Е Т F 12 Т Н **M3** (7)(2) (3) (4)(5) (6)

1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Circuit configuration:

E = TO-220AC 2L

A = TO-220AB 3L, common anode

4 - Package:

T = TO-220

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage code x 100 = V_{RRM} - 12 = 1200 V

7 - None = TO-220AB

• T = True pin TO-220

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

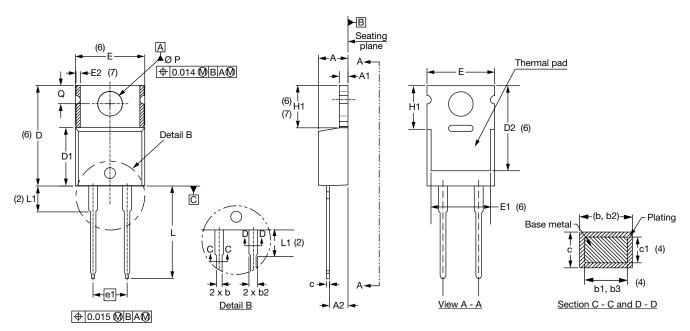
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-20ETF12THM3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96069					
Part marking information	www.vishay.com/doc?95391				
SPICE model www.vishay.com/doc?96866					



TO-220AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOIES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
E	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	ı	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Ø	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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